EPISTAR

ES-SMHRPX42C

AIGaInP PX-series LED Chip

> Mechanical Specification:

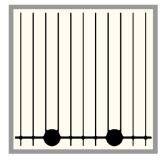
(1) Dimension

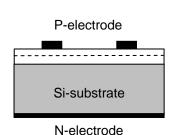
- Chip size: 42 mil x 42 mil (1070±25 μm x 1070±25 μm)

- Thickness: 8.8 mil (225±25 μ m) - P bonding pad: 4.7 mil (120±10 μ m)

(2) Metallization

Topside P electrode: Au alloy(x2)Backside N electrode: Au alloy





Features:

- · High luminous intensity
- · Thin film structure
- · Vertical electrode
- · High driving current

Applications:

- · Traffic signal
- ·Lighting

> Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward Voltage	Vf1		If = 10μA	1.3	-	-	V
	Vf2		If = 350mA	-	2.2	2.6	V
Reverse Current	Ir		Vr = 10V	-	-	5.0	μΑ
Peak Wavelength	λр		If = 350mA	-	631	-	nm
Dominant Wavelength ⁽¹⁾	λd		If = 350mA	619	624	629	nm
Spectra Half-width	Δλ		If = 350mA	-	20	-	nm
Luminous Intensity ⁽²⁾⁽³⁾	lv	H16	If = 350mA	15000	-	-	mcd
		H17		17000	-	-	
		H18		19000	-	-	

Note:

⁽¹⁾ Basically, the wavelength span is 10nm; however, customers' special requirements are also welcome.

 $[\]ensuremath{\text{(2)}}\xspace \ensuremath{\text{Customers'}}\xspace \ensuremath{\text{special}}\xspace \ensuremath{\text{requirements}}\xspace \ensuremath{\text{are}}\xspace \ensuremath{\text{also}}\xspace \ensuremath{\text{welcome.}}\xspace$

⁽³⁾ Luminous intensity is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25°C	≤ 700	mA
Reverse Voltage	Vr	Ta = 25°C	≤ 10	V
Junction Temperature	Tj	-	≤ 125	°C
Storage Temperature	Tstg	Chip	-40 ~ +85	°C
		Chip-on-tape/storage	5 ~ 35	°C
		Chip-on-tape/transportation	-20 ~ +65	°C
Temperature during Packaging	-	-	280(<10sec)	°C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 - Relative luminous Intensity vs. Forward Current

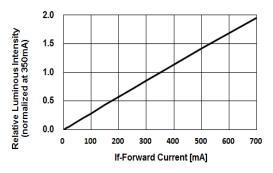


Fig.3 – Relative Intensity (@350mA) vs. Ambient Temperature

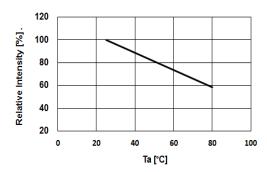


Fig.5 – Dominant Wavelength (@350mA) vs. Ambient Temperature

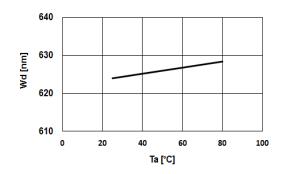


Fig.2 – Forward Current vs. Forward Voltage

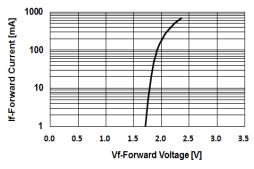
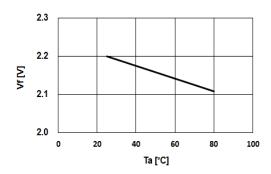


Fig.4 – Forward Voltage (@350mA) vs. Ambient Temperature



 $\begin{tabular}{ll} Fig. 6-Maximum Driving Forward DC Current vs. Ambient \\ Temperature (De-rating based on Tj max. = <math>125^{\circ}C$)

